

Silicon Nitride (Si₃N₄) Sputtering Targets

Material Type	Silicon Nitride	Theoretical Density (g/cc)	3.44
Symbol	Si ₃ N ₄	Z Ratio	**1.00
Color/Appearance	Gray, Crystalline Solid	Sputter	RF, RF-R
Melting Point (°C)	1,900	Max Power Density	20
Purity:	99.95%,99.99%	(Watts/Square Inch)	
		Type of Bond	Indium